



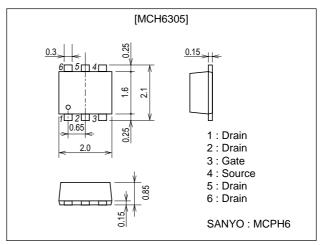
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm 2193



Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|--------|--|-------------|------|
| Drain-to-Source Voltage | VDSS | | -20 | V |
| Gate-to-Source Voltage | VGSS | | ±10 | V |
| Drain Current (DC) | ID | | -4 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | -16 | Α |
| Allowable Power Dissipation | PD | Mounted on a ceramic board (900mm ² X0.8mm) | 1.5 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|---|---------|-----|------|-------|
| | | | min | typ | max | Offic |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | ID=-1mA, VGS=0 | -20 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | V _{DS} =-20V, V _{GS} =0 | | | -1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | V _{GS} =±8V, V _{DS} =0 | | | ±10 | μА |
| Cutoff Voltage | VGS(off) | V _{DS} =-10V, I _D =-1mA | -0.4 | | -1.4 | V |
| Forward Transfer Admittance | yfs | V _D S=-10V, I _D =-2A | 4 | 5.8 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | I _D =-2A, V _G S=-4.5V | | 50 | 65 | mΩ |
| | Rps(on)2 | ID=-1A, VGS=-2.5V | | 72 | 98 | mΩ |

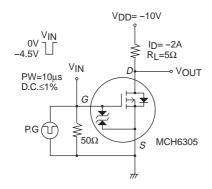
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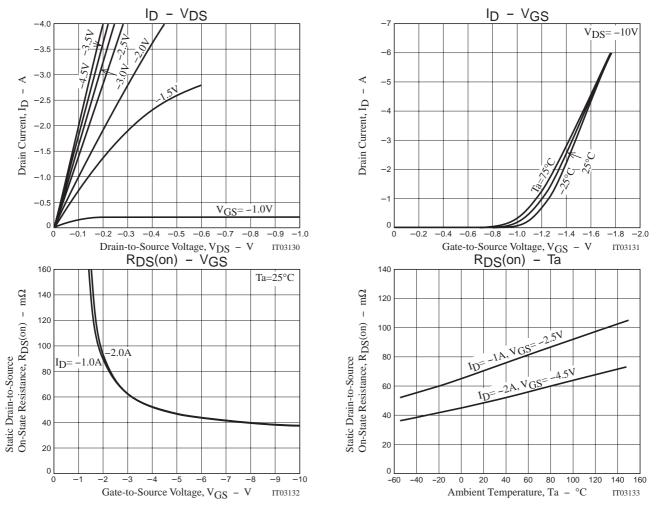
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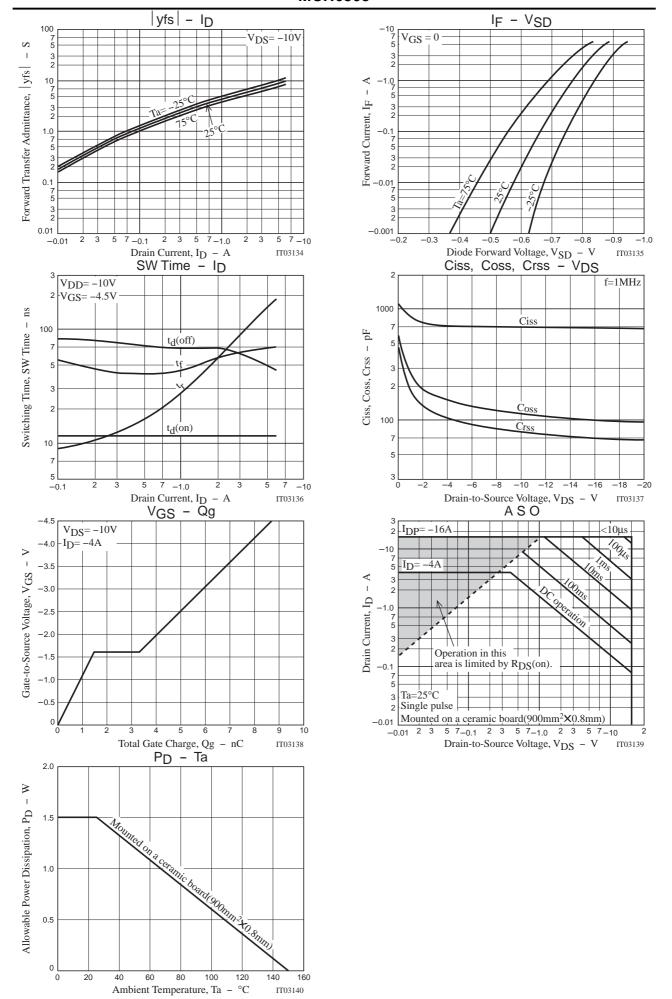
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|----------------------|--|---------|-------|------|------|
| | | | min | typ | max | Oill |
| Input Capacitance | Ciss | V _{DS} =-10V, f=1MHz | | 680 | | pF |
| Output Capacitance | Coss | V _{DS} =-10V, f=1MHz | | 115 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =-10V, f=1MHz | | 80 | | pF |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit | | 12 | | ns |
| Rise Time | tr | See specified Test Circuit | | 57 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit | | 68 | | ns |
| Fall Time | t _f | See specified Test Circuit | | 58 | | ns |
| Total Gate Charge | Qg | V _{DS} =-10V, V _{GS} =-4.5V, I _D =-4A | | 8.7 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =-10V, V _{GS} =-4.5V, I _D =-4A | | 1.5 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =-10V, V _{GS} =-4.5V, I _D =-4A | | 1.8 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =-4A, V _G S=0 | | -0.85 | -1.5 | V |

Switching Time Test Circuit





MCH6305



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